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INFORMATION DISCLOSURE (CITATION (Use several sheets if necessary)

Docket Number (Optional) NSC1-M2900 [P05632]	Application Number		
Applicant(s) Douglas Brisbin et al.	.,,		
Filing Date 7/9/2003	Group Art Unit & 815		

U.S. PATENT DOCUMENTS

*EXAMINER INITIAL	Ref	DOCUMENT NUMBER	DATE	Name	CLASS	SUBCLASS	Filing Date
Mel	AA	5,517,046	05/14/1996	Hsing et al.	257	336	02/06/1995
MCL	AB	6,144,069	11/07/2000	Tung	257	335	08/03/1999
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	DOCUMENT					TRANSLATION	
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1,100		reliability of an LDMOS transistor using drain ring over-drive bias," by Douglas Brisbin et al., 16 pages in length.
MCL	Al	U.S. Patent Application No. 10/266,543, filed October 8, 2002, entitled: "Method and device for improving hot carrier
MCL		Reliability Physics Symposium Proceedings 2002, pp. 105-110 (6 pages in length).
/	AH	D. Brisbin et al., "Hot Carrier Reliability of N-LDMOS Transistor Arrays for Power BiCMOS Applications," International
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21	AG	D. Brisbin et al., "Design Optimization of N-LDMOS Transistor Arrays for Hot Carrier Lifetime Enhancement,"

Examiner Nauth C. Laluy	Date Considered 9/14/04				
Examiner: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if					
not in conformance and not considered. Include copy of this form with next communication to applicant.					